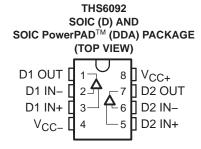
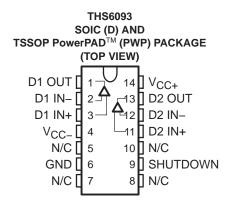
- Remote Terminal ADSL Line Driver
  - Ideal for Both Full Rate ADSL and G.Lite
  - Compatible With 1:2 Transformer Ratio
- Wide Supply Voltage Range +5 V to +14 V
  - Ideal for Single Supply +12-V Operation
- Low 2.1 pA/√Hz Noninverting Current Noise
  - Reduces Noise Feedback Through Hybrid Into Downstream Channel
- Wide Output Swing
  - 18.4 Vpp Differential Output Voltage,  $R_1 = 50 \Omega$ , 12-V Single Supply
- High Output Current
  - 275 mA (typ)



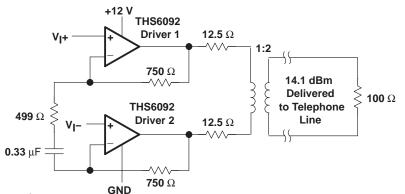
#### High Speed

- 100 MHz (-3 dB, G=1, 12-V Single Supply)
- 600 V/μs Slew Rate (G = 4, 12-V Single Supply)
- Low Distortion, Single-Ended, G = 4
  - 72 dBc (250 kHz, 2 Vpp, 25 Ω load)
  - 78 dBc (250 kHz, 2 Vpp, 100 Ω load)
- Low Power Shutdown (THS6093)
  - 300 μA Total Standby Current
- Thermal Shutdown and Short Circuit Protection
- Standard SOIC, SOIC PowerPAD™, and TSSOP PowerPAD™ Package
- Evaluation Module Available



#### description

The THS6092/3 is a high-speed line driver ideal for driving signals from the remote terminal to the central office in asymmetrical digital subscriber line (ADSL) applications. It can operate from a single +12-V supply voltage while drawing only 7.3 mA of supply current per channel. It offers low –72 dBc total harmonic distortion driving a 25- $\Omega$  load (2 Vpp). The THS6092/3 offers a high 18.4-Vpp differential output swing across a 50- $\Omega$  load from a single +12-V supply. The THS6093 features a low-power shutdown mode, consuming only 300  $\mu$ A quiescent current per channel. The THS6092/3 is packaged in a standard SOIC, SOIC PowerPAD<sup>TM</sup>, and TSSOP PowerPAD<sup>TM</sup> package.



#### **RELATED PRODUCTS**

DEVICE	DESCRIPTION
THS6042/3	350-mA, ±12 ADSL CPE line driver
THS6052/3	175-mA, $\pm$ 12 V ADSL CPE line driver
OPA2677	380-mA, +12 V ADSL CPE line driver
THS6062	Low noise ADSL receiver



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

PowerPAD is a trademark of Texas Instruments.

TEXAS INSTRUMENTS

#### **AVAILABLE OPTIONS**

		PACKAGED DEVICE					
TA	SOIC-8† (D)	SOIC-8† PowerPAD (DDA)	PAD SOIC-141 PowerPAD		EVALUATION MODULES		
0°C to 70°C	THS6092CD	THS6092CDDA	THS6093CD	THS6093CPWP	THS6092EVM THS6093EVM		
-40°C to 85°C	THS6092ID	THS6092IDDA	THS6093ID	THS6093IPWP	_		

<sup>†</sup> All packages are available taped and reeled. Add an R-suffix to the device type (i.e., THS6092IDR).

# absolute maximum ratings over operating free-air temperature (unless otherwise noted)†

Supply voltage, V <sub>CC+</sub> to V <sub>CC-</sub>	14.7 V
Input voltage	
Output current (see Note 1)	350 mA
Differential input voltage	± 3 V
Maximum junction temperature	150°C
Total power dissipation at (or below) 25°C free-air temperature	See Dissipation Ratings Table
Operating free-air temperature, T <sub>A</sub> : Commercial	0°C to 70°C
Industrial	–40°C to 85°C
Storage temperature, T <sub>stq</sub> : Commercial	–65°C to 125°C
Industrial	
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	300°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The THS6092 and THS6093 may incorporate a PowerPAD™ on the underside of the chip. This acts as a heatsink and must be connected to a thermally dissipating plane for proper power dissipation. Failure to do so may result in exceeding the maximum junction temperature which could permanently damage the device. See TI Technical Brief SLMA002 for more information about utilizing the PowerPAD™ thermally enhanced package.

#### **DISSIPATION RATING TABLE**

PACKAGE	$AL^{\theta}$	θЈС	T <sub>A</sub> = 25°C§ POWER RATING	T <sub>A</sub> = 70°C§ POWER RATING	T <sub>A</sub> = 85°C§ POWER RATING
D-8	95°C/W <sup>‡</sup>	38.3°C/W <sup>‡</sup>	1.1 W	0.63 W	0.47 W
DDA	45.8°C/W	9.2°C/W	2.3 W	1.31 W	0.98 W
D-14	66.6°C/W‡	26.9°C/W‡	1.6 W	0.90 W	0.68 W
PWP	37.5°C/W	1.4°C/W	2.8 W	1.60 W	1.20 W

<sup>&</sup>lt;sup>‡</sup> This data was taken using the JEDEC proposed high-K test PCB. For the JEDEC low-K test PCB, the Θ<sub>JA</sub> is168°C/W for the D–8 package and 122.3°C/W for the D–14 package.

## recommended operating conditions

		MIN	NOM MAX	UNIT
Complementaria VIII - ta VIII -	Dual supply	±2.5	±7	.,
Supply voltage, V <sub>CC+</sub> to V <sub>CC-</sub>	Single supply	+5	+14	V
On another free sintense and as T	C-suffix	0	70	
Operating free-air temperature, T <sub>A</sub>	I-suffix	-40	85	°C



<sup>§</sup> Power rating is determined with a junction temperature of 130°C. This is the point where distortion starts to substantially increase. Thermal management of the final PCB should strive to keep the junction temperature at or below 125°C for best performance.

electrical characteristics over recommended operating free-air temperature range, T<sub>A</sub> = 25°C, V<sub>CC+</sub> = 12 V, V<sub>CC-</sub> = GND, R<sub>FEEDBACK</sub> = 750  $\Omega$ , R<sub>L</sub> = 25  $\Omega$  (unless otherwise noted)

## dynamic performance

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
BW Small-signal bandwidth (– 3 dB) G=1		V <sub>CC</sub> = 12 V		100		MHz
BW	Small-signal bandwidth (-3 dB) G=1	V <sub>CC</sub> = 5 V		90		IVIHZ
CD	Claurate (see Note 2)	V <sub>CC</sub> = 12 V		600		Mora
SR	Slew rate (see Note 2)	V <sub>CC</sub> = 5 V		400		V/μs

NOTE 2: Slew rate is defined from the 25% to the 75% output levels.

## noise/distortion performance

	PARAMETER		TEST CON	TEST CONDITIONS			MAX	UNIT	
Total harmonic distortion		Gain = 4, $R_L = 25 \Omega$ , $V_{CC} = 5 V$ , $f = 250 \text{ kHz}$	V <sub>O(pp)</sub> = 2 V		-70				
THD	(single-ended configuration)		Gain = 4, $R_L = 25 \Omega$ ,	V <sub>O(pp)</sub> = 2 V		-72		dBc	
		$V_{CC} = 12 \text{ V},  f = 250 \text{ kHz}$	V <sub>O(pp)</sub> = 7 V	-68					
٧n	Input voltage noise		V <sub>CC</sub> = 12 V, 5 V, f = 10 kHz			2.1		nV/√Hz	
	lanut aurrant naisa	+Input	V 12 V E V 1 10 H I=	V 40 V 5 V 5 40 H =		2.1		pA/√Hz	
In	Input current noise	-Input	V <sub>CC</sub> = 12 V, 5 V, f = 10 kHz		10.9			pA/√HZ	
XT	Crosstalk		$ \begin{array}{ll} \mbox{f = 250 kHz} \;, & \mbox{V}_{\mbox{O}} = 2 \; \mbox{Vpp} \\ \mbox{G = 4}, & \mbox{R}_{\mbox{L}} = 25 \; \Omega \\ \end{array} $	V <sub>CC</sub> = 5 V		-65		dBc	
				V <sub>CC</sub> = 12 V		-63			

#### dc performance

	PARAMETER	TEST C	ONDITIONS	MIN	TYP	MAX	UNIT
	lanut offect voltage		T <sub>A</sub> = 25°C		6	16	
	Input offset voltage		T <sub>A</sub> = full range			21	\/
Vos	Differential offset voltage	V <sub>CC</sub> = 12 V, 5 V	T <sub>A</sub> = 25°C		1	6	mV
	Differential offset voltage		T <sub>A</sub> = full range			8	
	Offset drift		T <sub>A</sub> = full range	20			μV/°C
	- Input bias current		T <sub>A</sub> = 25°C		3	10	
	- Input bias current		T <sub>A</sub> = full range			12	
l.n	I lanut biog ourrent	\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	$T_A = 25^{\circ}C$		1	6	^
IB	+ Input bias current	V <sub>CC</sub> = 12 V, 5 V	T <sub>A</sub> = full range			7	μΑ
	Differential input bias current		T <sub>A</sub> = 25°C		3	10	
	Differential input bias current		T <sub>A</sub> = full range			12	
ZOL	Open loop transimpedance	$R_L = 1 k\Omega$	V <sub>CC</sub> = 12 V, 5 V		0.9		$M\Omega$

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electrical characteristics over recommended operating free-air temperature range, T<sub>A</sub> = 25°C, V<sub>CC+</sub> = 12 V, V<sub>CC-</sub> = GND, R<sub>FEEDBACK</sub> = 750  $\Omega$ , R<sub>L</sub> = 25  $\Omega$  (unless otherwise noted) (continued)

## input characteristics

PARAMETER		TEST CONDI	TIONS	MIN	TYP	MAX	UNIT
		V <sub>CC</sub> = 5 V	T <sub>A</sub> = 25°C	1.5 to 3.5	1.1 to 3.9		
V	lanut common mode valtage ronge	ACC = 2 A	T <sub>A</sub> = full range	1.6 to 3.4			.,
V <sub>ICR</sub> Ir	Input common-mode voltage range	V 40 V	T <sub>A</sub> = 25°C	2.3 to 9.7	1.8 to 10.2		V
		V <sub>CC</sub> = 12 V	T <sub>A</sub> = full range	2.4 to 9.6			
		V <sub>CC</sub> = 5 V	T <sub>A</sub> = 25°C	56	63		
CMRR			T <sub>A</sub> = full range	54			dB
CIVIKK	Common-mode rejection ratio	V 40 V	T <sub>A</sub> = 25°C	50	56		uБ
		V <sub>CC</sub> = 12 V	T <sub>A</sub> = full range	48			
D.	Innuit vaniatores	+ Input			1		МΩ
R <sub>I</sub>	Input resistance	-Input			15		Ω
CI	Input capacitance				2		pF

## output characteristics

	PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
			D 05.0	V <sub>CC</sub> = 5 V	1.4 to 3.6	1.1 to 3.9		
.,	Va Output voltage cwing	Single ended	$R_L = 25 \Omega$	V <sub>CC</sub> = 12 V	1.9 to 10.1	1.4 to 10.6		.,
۷O		100 mV overdrive	e R <sub>L</sub> = 100 Ω	V <sub>C</sub> C = 5 V	1.3 to 3.7	1.05 to 3.95		V
				V <sub>CC</sub> = 12 V	1.5 to 10.5	1.1 to 10.9		
	Output summer!		$R_L = 3.6 \Omega$ ,	V <sub>C</sub> C = 5 V		240		4
IO	Output current		$R_L = 10 \Omega$ ,	V <sub>CC</sub> = 12 V	240	275		mA
Isc	Short-circuit current		$R_L = 0 \Omega$ ,	V <sub>CC</sub> = 12 V		325		mA
	Output resistance		Open loop			15		Ω

## power supply

	PARAMETER			TEST CONDITIONS		TYP	MAX	UNIT
		Dual supply					±7	.,
vcc	V <sub>CC</sub> Operating range				4.5		14	V
			., 5.,	T <sub>A</sub> = 25°C		6.7	8.8	4
I <sub>CC</sub> Quiescent current (each driver)		V <sub>CC</sub> = 5 V	T <sub>A</sub> = full range			10	mA	
	Quiescent current (each driver)	r)	.,	T <sub>A</sub> = 25°C		7.3	9.5	4
			V <sub>CC</sub> = 12 V	T <sub>A</sub> = full range			10.5	mA
			.,	T <sub>A</sub> = 25°C	-54	-58		
D0DD	Barrer and the state of the state of		$V_{CC} = 5 V$	T <sub>A</sub> = full range	-46	-		.15
PSRR	Power supply rejection ratio		10.11	T <sub>A</sub> = 25°C	-58	-70		dB
			V <sub>CC</sub> = 12 V	T <sub>A</sub> = full range	-50			



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electrical characteristics over recommended operating free-air temperature range,  $T_A$  = 25°C,  $V_{CC+}$  = 12 V,  $V_{CC-}$  = GND,  $R_{FEEDBACK}$  = 750  $\Omega$ ,  $R_L$  = 25  $\Omega$  (unless otherwise noted) (continued)

## shutdown characteristics (THS6093 only)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
VIL(SHDN)	Shutdown pin voltage for power up	V <sub>CC</sub> = 12 V, GND = 6 V (GND Pin as Reference)			0.8	V
VIH(SHDN)	Shutdown pin voltage for power down	V <sub>CC</sub> = 12 V, GND = 6 V (GND Pin as Reference)	2			V
ICC(SHDN)	Total quiescent current when in shutdown state	V <sub>SHDN</sub> = 8 V, V <sub>GND</sub> = 6 V, V <sub>CC</sub> = 12 V		0.3	0.7	mA
tDIS	Disable time (see Note 3)	V <sub>CC</sub> = 12 V		0.2		μs
tEN	Enable time (see Note 3)	V <sub>CC</sub> = 12 V		0.5		μs
IL(SHDN)	Shutdown pin input bias current for power up	V <sub>SHDN</sub> = 6 V, V <sub>GND</sub> = 6 V, V <sub>CC</sub> = 12 V		40	100	μΑ
IH(SHDN)	Shutdown pin input bias current for power down	V <sub>SHDN</sub> = 9.3 V, V <sub>GND</sub> = 6 V, V <sub>CC</sub> = 12 V		50	100	μΑ

NOTE 3: Disable/enable time is defined as the time from when the shutdown signal is applied to the SHDN pin to when the supply current has reached half of its final value.

## **APPLICATION INFORMATION**

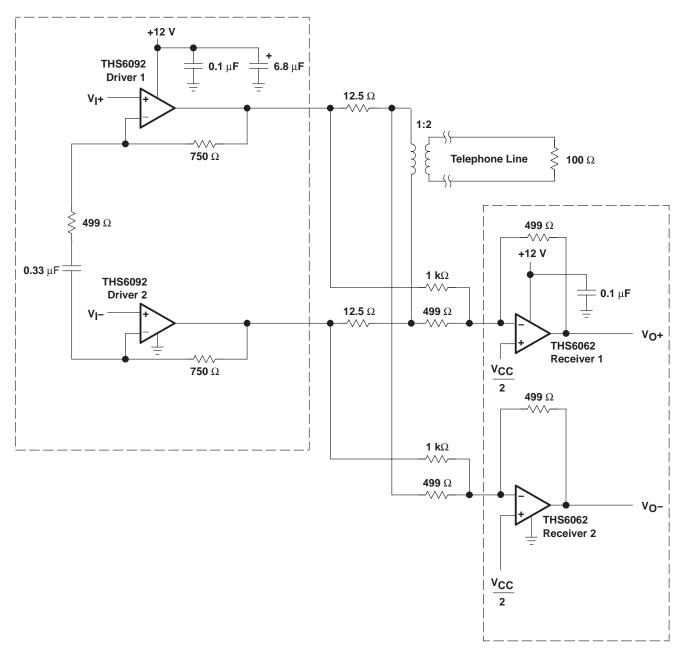


Figure 1. THS6092 ADSL Application With 1:2 Transformer Ratio



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#### **PACKAGING INFORMATION**

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
THS6092ID	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	60921	Samples
THS6093CPWPR	ACTIVE	HTSSOP	PWP	14	2000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	0 to 70	HS6093C	Samples
THS6093IPWP	ACTIVE	HTSSOP	PWP	14	90	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	HS6093I	Samples
THS6093IPWPR	ACTIVE	HTSSOP	PWP	14	2000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	HS6093I	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE**: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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## **PACKAGE OPTION ADDENDUM**

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

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## TAPE AND REEL INFORMATION





		Dimension designed to accommodate the component width
		Dimension designed to accommodate the component length
	K0	Dimension designed to accommodate the component thickness
	W	Overall width of the carrier tape
Γ	P1	Pitch between successive cavity centers

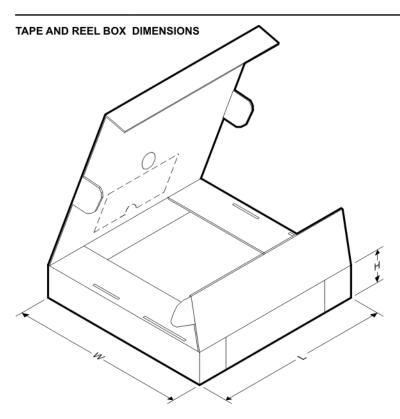
## QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
THS6093CPWPR	HTSSOP	PWP	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
THS6093IPWPR	HTSSOP	PWP	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

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#### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
THS6093CPWPR	HTSSOP	PWP	14	2000	350.0	350.0	43.0
THS6093IPWPR	HTSSOP	PWP	14	2000	350.0	350.0	43.0

# PACKAGE MATERIALS INFORMATION

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## **TUBE**



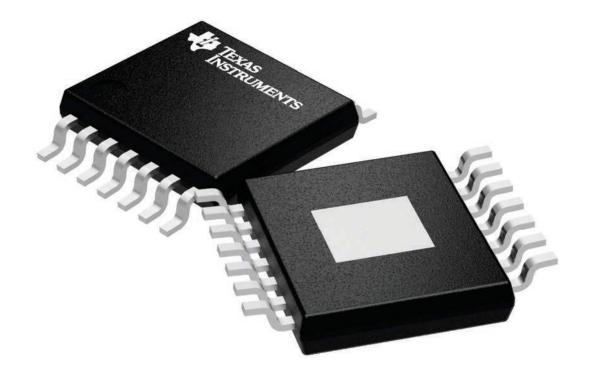
#### \*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
THS6092ID	D	SOIC	8	75	505.46	6.76	3810	4
THS6093IPWP	PWP	HTSSOP	14	90	530	10.2	3600	3.5

4.4 x 5.0, 0.65 mm pitch

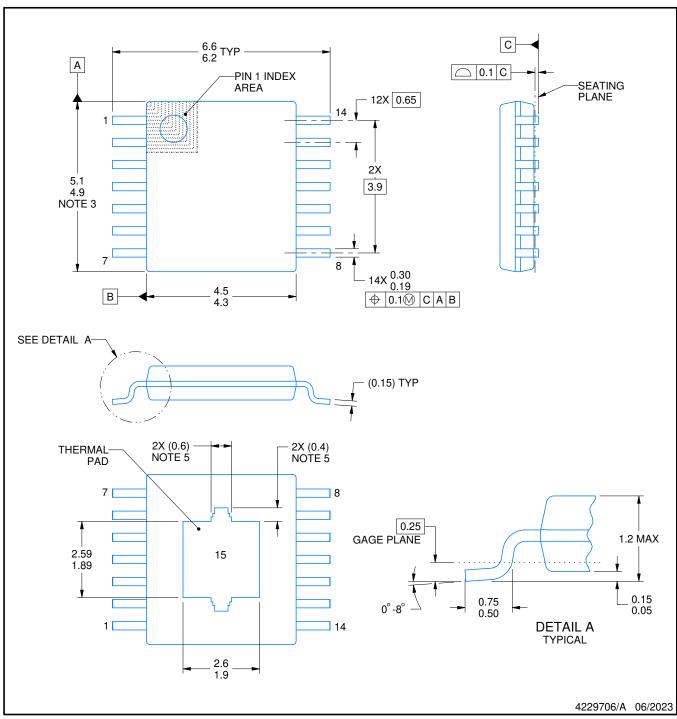
PLASTIC SMALL OUTLINE

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



# PowerPAD<sup>™</sup> TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



#### NOTES:

PowerPAD is a trademark of Texas Instruments.

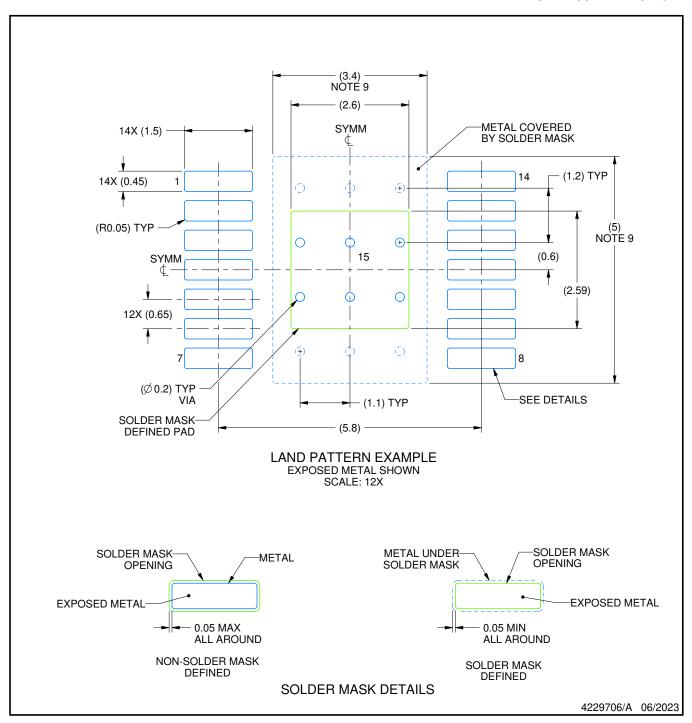
- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
  4. Reference JEDEC registration MO-153.
- 5. Features may differ or may not be present.



SMALL OUTLINE PACKAGE

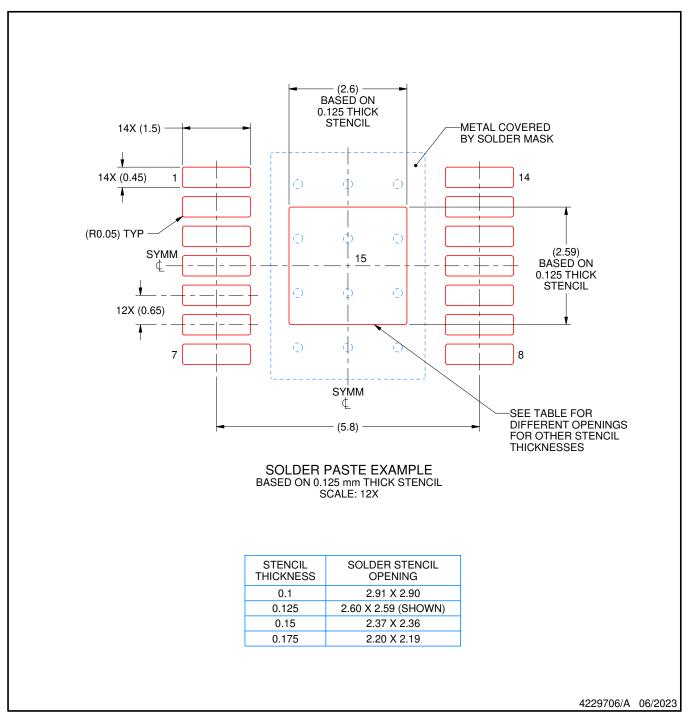


NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
- 8. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature numbers SLMA002 (www.ti.com/lit/slma002) and SLMA004 (www.ti.com/lit/slma004).
- 9. Size of metal pad may vary due to creepage requirement.
- 10. Vias are optional depending on application, refer to device data sheet. It is recommended that vias under paste be filled, plugged or tented.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 12. Board assembly site may have different recommendations for stencil design.



# **PACKAGE OUTLINE**

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



## NOTES:

- 1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.5. Reference JEDEC registration MS-012, variation AA.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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